Single Low Noise Operational Amplifier

The NE/SA/SE5534/5534A are single high-performance low noise operational amplifiers. Compared to other operational amplifiers, such as TL083, they show better noise performance, improved output drive capability, and considerably higher small-signal and power bandwidths.

This makes the devices especially suitable for application in high quality and professional audio equipment, in instrumentation and control circuits and telephone channel amplifiers. The op amps are internally compensated for gain equal to, or higher than, three. The frequency response can be optimized with an external compensation capacitor for various applications (unity gain amplifier, capacitive load, slew rate, low overshoot, etc.).

Features

• Small-Signal Bandwidth: 10 MHz

• Output Drive Capability: 600 Ω , 10 V_{RMS} at V_S = \pm 18 V

Input Noise Voltage: 4 nV/√Hz

• DC Voltage Gain: 100000

• AC Voltage Gain: 6000 at 10 kHz

• Power Bandwidth: 200 kHz

• Slew Rate: 13 V/μs

• Large Supply Voltage Range: ± 3.0 to ± 20 V

Applications

Audio Equipment

• Instrumentation and Control Circuits

• Telephone Channel Amplifiers

• Medical Equipment



ON Semiconductor®

http://onsemi.com

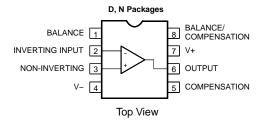


SOIC-8 D SUFFIX CASE 751



PDIP-8 N SUFFIX CASE 626

PIN CONNECTIONS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 10 of this data sheet.

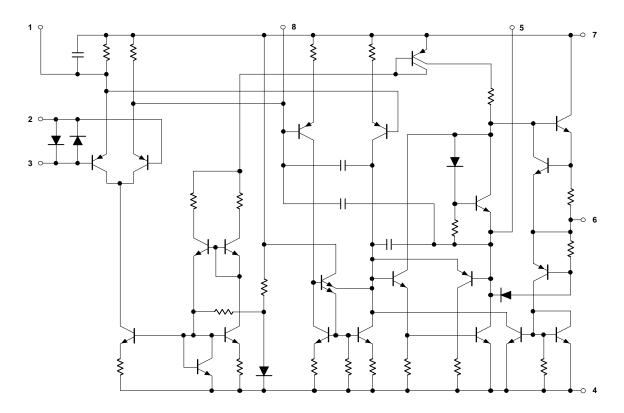


Figure 1. Equivalent Schematic

MAXIMUM RATINGS

Rating		Symbol	Value	Unit
Supply Voltage		V _S	±22	V
Input Voltage		V _{IN}	± V Supply	V
Differential Input Voltage (Note 1)		V_{DIFF}	±0.5	V
Operating Temperature Range NE SA SE		T _{amb}	0 to +70 -40 to +85 -55 to +125	°C
Storage Temperature Range		T _{stg}	-65 to +150	°C
Junction Temperature		Tj	150	°C
Power Dissipation at 25°C	N Package D Package	P _D	1150 750	mW
Thermal Resistance, Junction-to-Ambient	N Package D Package	$R_{ hetaJA}$	130 158	°C/W
Output Short-Circuit Duration (Note 2)		_	Indefinite	-
Lead Soldering Temperature (10 sec max)		T _{sld}	230	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

^{1.} Diodes protect the inputs against overvoltage. Therefore, unless current-limiting resistors are used, large currents will flow if the differential input

voltage exceeds 0.6 V. Maximum current should be limited to ±10 mA.

2. Output may be shorted to ground at V_S = ±15 V, T_{amb} = 25°C. Temperature and/or supply voltages must be limited to ensure dissipation rating is not exceeded.

DC ELECTRICAL CHARACTERISTICS ($T_{amb} = 25^{\circ}C$; $V_{S} = \pm 15$ V, unless otherwise noted.) (Notes 3, 4 and 5)

			NE/SA5534/5534A			SI	E5534/553	4A	
Characteristic	Symbol	Test Conditions	Min	Тур	Max	Min	Тур	Max	Unit
	Vos		_	0.5	4.0	_	0.5	2.0	mV
Offset Voltage		Overtemperature	_	_	5.0	_	_	3.0	mV
	$\Delta V_{OS}/\Delta T$		-	5.0	_	_	5.0	-	μV/°C
	I _{OS}		_	20	300	_	10	200	nA
Offset Current		Overtemperature	_	_	400	_	_	500	nA
	$\Delta I_{OS}/\Delta T$		-	200	_	_	200	-	pA/°C
	I _B		-	500	1500	-	400	800	nA
Input Current		Overtemperature	_	_	2000	_	_	1500	nA
	$\Delta I_{B}/\Delta T$		_	5.0	_	_	5.0	_	nA/°C
Supply Current Per Op Amp	I _{CC}	Overtemperature		4.0 -	8.0 10	_ _	4.0 -	6.5 9.0	mA
Common Mode Input Range Common Mode Rejection Ratio Power Supply Rejection Ratio	V _{CM} CMRR PSRR		±12 70 -	±13 100 10	- - 100	±12 80 -	±13 100 10	- - 50	V dB μV/V
Large-Signal Voltage Gain	A _{VOL}	$R_L \ge 600 \Omega$,	25	100	_	50	100	-	V/mV
		$V_0 = \pm 10 \text{ V}$ Overtemperature	15	_	_	25	_	_	
Output Swing	V _{OUT}	$R_L \ge 600 \Omega$	±12	±13	-	±12	±13	-	V
		Overtemperature $R_L \ge 600 \Omega$; $V_S = \pm 18 V$	±10 ±15	±12 ±16	- -	±10 ±15	±12 16	- -	
		$R_L \ge 2.0 \text{ k}\Omega$ Overtemperature	±13 ±12	±13.5 ±12.5	-	±13 ±12	±13.5 ±12.5	- -	
Input Resistance	R _{IN}		30	100	_	50	100	_	kΩ
Output Short Circuit Current	I _{SC}		_	38	_	_	38	_	mA

^{3.} For NE5534/5534A, T_{MIN} = 0°C, T_{MAX} = 70°C. 4. For SA5534/5534A, T_{MIN} = -40°C, T_{MAX} = +85°C. 5. For SE5534/5534A, T_{MIN} = -55°C, T_{MAX} = +125°C.

AC ELECTRICAL CHARACTERISTICS (T_{amb} = 25° C; V_S = \pm 15 V, unless otherwise noted.)

			NE/	SA5534/5	534A	SI	E5534/553	4A	
Characteristic	Symbol	Test Conditions	Min	Тур	Max	Min	Тур	Max	Unit
Output Resistance	Rout	$\begin{aligned} A_V &= 30 \text{ dB} \\ \text{closed-loop} \\ f &= 10 \text{ kHz}; \\ R_L &= 600 \ \Omega; \\ C_C &= 22 \text{ pF} \end{aligned}$	-	0.3	-	-	0.3	-	Ω
Transient Response		$\label{eq:Voltage-follower} \begin{split} & \text{Voltage-follower} \\ & \text{V}_{\text{IN}} = 50 \text{ mV} \\ & \text{R}_{\text{L}} = 600 \ \Omega, \\ & \text{C}_{\text{C}} = 22 \text{ pF}, \\ & \text{C}_{\text{L}} = 100 \text{ pF} \end{split}$							
Rise Time	t _R		_	20	_	_	20	_	ns
Overshoot	_		-	20	_	-	20	-	%
Transient Response		$V_{IN} = 50 \text{ mV},$ $R_L = 600 \Omega,$ $C_C = 47 \text{ pF},$ $C_L = 500 \text{ pF}$							
Rise Time	t _R		_	50	_	_	50	_	ns
Overshoot	_		_	35	_	_	35	_	%
Gain	A _V	$f = 10 \text{ kHz}, C_C = 0$	_	6.0	_	_	6.0	_	V/mV
		f = 10 kHz, C _C = 22 pF	_	2.2	_	_	2.2	_	
Gain Bandwidth Product	GBW	$C_C = 22 \text{ pF},$ $C_L = 100 \text{ pF}$	-	10	_	-	10	-	MHz
Slew Rate	SR	C _C = 0	-	13	_	-	13	-	V/μs
		$C_C = 22 pF$	_	6.0	_	_	6.0	_	
Power Bandwidth	-	$V_{OUT} = \pm 10 \text{ V},$ $C_C = 0 \text{ pF}$	-	200	-	-	200	-	kHz
		$V_{OUT} = \pm 10 \text{ V},$ $C_C = 22 \text{ pF}$	-	95	_	-	95	_	
		$V_{OUT} = \pm 14 \text{ V},$ $R_L = 600 \Omega,$ $C_C = 22 \text{ pF},$ $V_{CC} = \pm 18 \text{ V}$	-	70	_	_	70	_	

ELECTRICAL CHARACTERISTICS ($T_{amb} = 25$ °C; $V_{S} = 15$ V, unless otherwise noted.)

			NE/SA/SE5534		NE/SA/SE5534A		34A		
Characteristic	Symbol	Test Conditions	Min	Тур	Max	Min	Тур	Max	Unit
Input Noise Voltage	V _{NOISE}	$f_O = 30 \text{ Hz}$ $f_O = 1.0 \text{ kHz}$	-	7.0 4.0	-		5.5 3.5	7.0 4.5	nV/√Hz
Input Noise Current	I _{NOISE}	$f_O = 30 \text{ Hz}$ $f_O = 1.0 \text{ kHz}$	-	2.5 0.6	-		1.5 0.4	-	pA/√Hz
Broadband Noise Figure	-	f = 10 Hz to 20 kHz; R_S = 5.0 kΩ	-	-	-	-	0.9	-	dB
Channel Separation	-	$f = 1.0 \text{ kHz};$ $R_S = 5.0 \text{ k}\Omega$	-	110	-	_	110	-	dB

TYPICAL PERFORMANCE CHARACTERISTICS

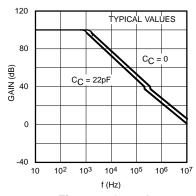


Figure 2. Open-Loop Frequency Response

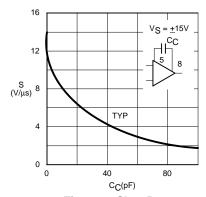


Figure 3. Slew Rate as a Function of Compensation Capacitance

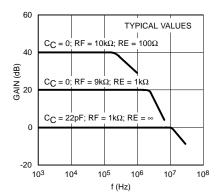


Figure 4. Closed-Loop Frequency Response

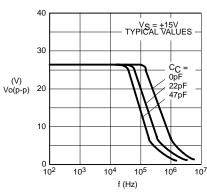


Figure 5. Large-Signal Frequency Response

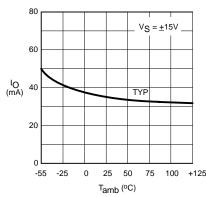


Figure 6. Output Short-Circuit Current

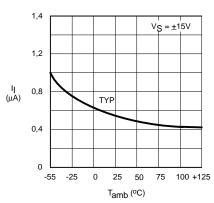


Figure 7. Input Bias Current

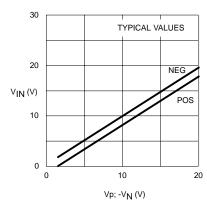


Figure 8. Input Common-Mode Voltage Range

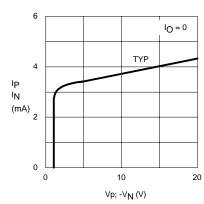


Figure 9. Supply Current Per Op Amp

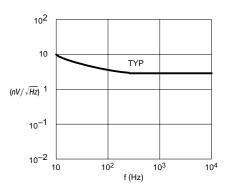


Figure 10. Input Noise Voltage Density

TYPICAL PERFORMANCE CHARACTERISTICS

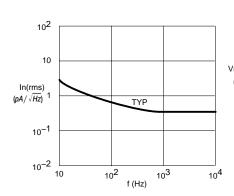


Figure 11. Input Noise Current Density

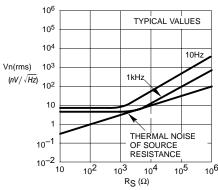


Figure 12. Total Input Noise Density

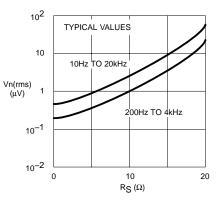


Figure 13. Broadband Input Noise Voltage

TEST LOAD CIRCUITS

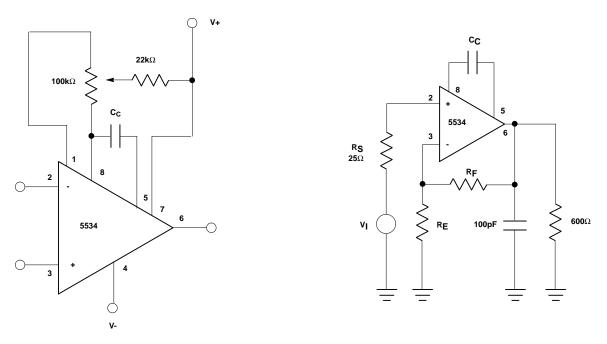


Figure 14. Frequency Compensation and Offset Voltage Adjustment Circuit

Figure 15. Closed-Loop Frequency Response

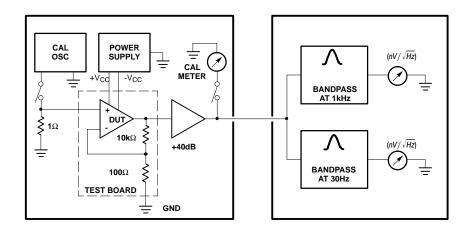


Figure 16. Noise Test Block Diagram

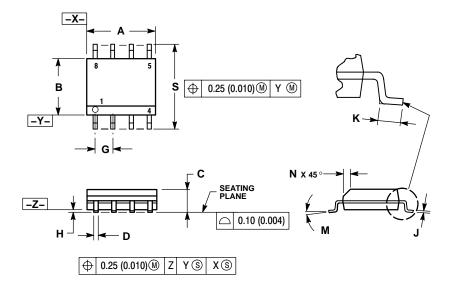
ORDERING INFORMATION

Device	Description	Temperature Range	Shipping†
NE5534AD	8-Pin Plastic Small Outline Package	0 to +70°C	98 Units/Rail
NE5534ADR2	8-Pin Plastic Small Outline Package	0 to +70°C	2500 Tape & Reel
NE5534AN	8-Pin Plastic Dual In-Line Package	0 to +70°C	50 Units/Rail
NE5534D	8-Pin Plastic Small Outline Package	0 to +70°C	98 Units/Rail
NE5534DR2	8-Pin Plastic Small Outline Package	0 to +70°C	2500 Tape & Reel
NE5534N	8-Pin Plastic Dual In-Line Package	0 to +70°C	50 Units/Rail
SA5534AD	8-Pin Plastic Small Outline Package	-40 to +85°C	98 Units/Rail
SA5534ADR2	8-Pin Plastic Small Outline Package	-40 to +85°C	2500 Tape & Reel
SA5534AN	8-Pin Plastic Dual In-Line Package	-40 to +85°C	50 Units/Rail
SA5534N	8-Pin Plastic Dual In-Line Package	-40 to +85°C	50 Units/Rail
SE5534AN	8-Pin Plastic Dual In-Line Package	–55 to +125°C	50 Units/Rail
SE5534N	8-Pin Plastic Dual In-Line Package	–55 to +125°C	50 Units/Rail

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

PACKAGE DIMENSIONS

SOIC-8 NB **D SUFFIX** CASE 751-07 **ISSUE AB**



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- ANSI Y14-5M, 1982.

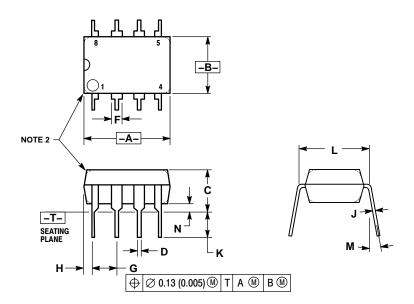
 2. CONTROLLING DIMENSION: MILLIMETER.

 3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.

 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006)
- PER SIDE.
 5. DIMENSION D DOES NOT INCLUDE DAMBAR
 PROTRUSION. ALLOWABLE DAMBAR
 PROTRUSION SHALL BE 0.127 (0.005) TOTAL
 IN EXCESS OF THE D DIMENSION AT
 MAXIMUM MATERIAL CONDITION.
 6. 751-01 THRU 751-06 ARE OBSOLETE. NEW
- STANDARD IS 751-07.

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	4.80	5.00	0.189	0.197	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.053	0.069	
D	0.33	0.51	0.013	0.020	
G	1.27	7 BSC	0.050 BSC		
Н	0.10	0.25	0.004	0.010	
J	0.19	0.25	0.007	0.010	
K	0.40	1.27	0.016	0.050	
М	0 °	8 °	0 °	8 °	
N	0.25	0.50	0.010	0.020	
S	5.80	6.20	0.228	0.244	

PDIP-8 **N SUFFIX** CASE 626-05 **ISSUE L**



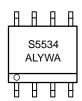
- 1. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
 2. PACKAGE CONTOUR OPTIONAL (ROUND OR SOUARE CORNERS).
 3. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

	MILLIN	IETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	9.40	10.16	0.370	0.400	
В	6.10	6.60	0.240	0.260	
С	3.94	4.45	0.155	0.175	
D	0.38	0.51	0.015	0.020	
F	1.02	1.78	0.040	0.070	
G	2.54	BSC	0.100 BSC		
Н	0.76	1.27	0.030	0.050	
J	0.20	0.30	0.008	0.012	
K	2.92	3.43	0.115	0.135	
L	7.62 BSC		0.300	BSC	
M		10°		10°	
N	0.76	1.01	0.030	0.040	

MARKING DIAGRAMS









PDIP-8 N SUFFIX CASE 626













A = Assembly Location

WL, L = Wafer Lot YY, Y = Year WW, W = Work Week

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